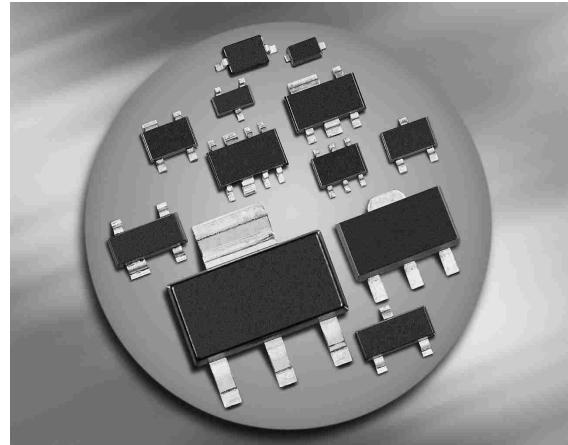


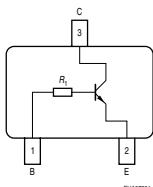
### NPN silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in resistor ( $R_1=4.7\text{k}\Omega$ )
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package

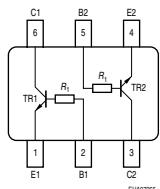


**BCR119/F/L3  
BCR119T/W**

**BCR119S  
SEMH7**



EH407364



EH407365

Type	Marking	Pin Configuration							Package
BCR119	WKS	1=B	2=E	3=C	-	-	-	-	SOT23
BCR119F	WKS	1=B	2=E	3=C	-	-	-	-	TSFP-3
BCR119L3	WK	1=B	2=E	3=C	-	-	-	-	TSLP-3-4
BCR119S	WKS	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	-	SOT363
BCR119T	WKS	1=B	2=E	3=C	-	-	-	-	SC75
BCR119W	WKS	1=B	2=E	3=C	-	-	-	-	SOT323
SEMH7	WK	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	-	SOT666

**Maximum Ratings**

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	50	V
Collector-base voltage	$V_{CBO}$	50	
Emitter-base voltage	$V_{EBO}$	5	
Input on voltage	$V_{i(on)}$	15	
DC collector current	$I_E$	100	mA
Total power dissipation- BCR119, $T_S \leq 102^\circ\text{C}$ BCR119F, $T_S \leq 128^\circ\text{C}$ BCR119L3, $T_S \leq 135^\circ\text{C}$ BCR119S, $T_S \leq 115^\circ\text{C}$ BCR119T, $T_S \leq 109^\circ\text{C}$ BCR119W, $T_S \leq 124^\circ\text{C}$ SEMH7, $T_S \leq 75^\circ\text{C}$	$P_{tot}$	200 250 250 250 250 250 250	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-65 ... 150	

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup> BCR119 BCR119F BCR119L3 BCR119S BCR119T BCR119W SEMH7	$R_{thJS}$	$\leq 240$ $\leq 90$ $\leq 60$ $\leq 140$ $\leq 165$ $\leq 105$ $\leq 300$	K/W

<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

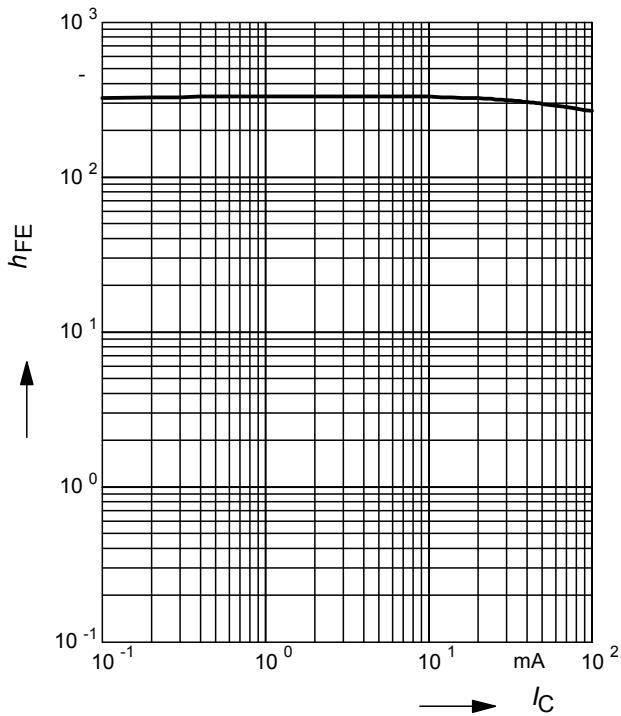
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Emitter-base breakdown voltage $I_E = 10 \mu\text{A}, I_C = 0$	$V_{(\text{BR})\text{EBO}}$	5	-	-	
Collector-base cutoff current $V_{\text{CB}} = 40 \text{ V}, I_E = 0$	$I_{\text{CBO}}$	-	-	100	nA
DC current gain <sup>1)</sup> $I_C = 5 \text{ mA}, V_{\text{CE}} = 5 \text{ V}$	$h_{\text{FE}}$	120	-	630	-
Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	$V_{\text{CEsat}}$	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{\text{CE}} = 5 \text{ V}$	$V_{i(\text{off})}$	0.4	-	0.8	
Input on voltage $I_C = 2 \text{ mA}, V_{\text{CE}} = 0.3 \text{ V}$	$V_{i(\text{on})}$	0.5	-	1.1	
Input resistor	$R_1$	3.2	4.7	6.2	k $\Omega$

**AC Characteristics**

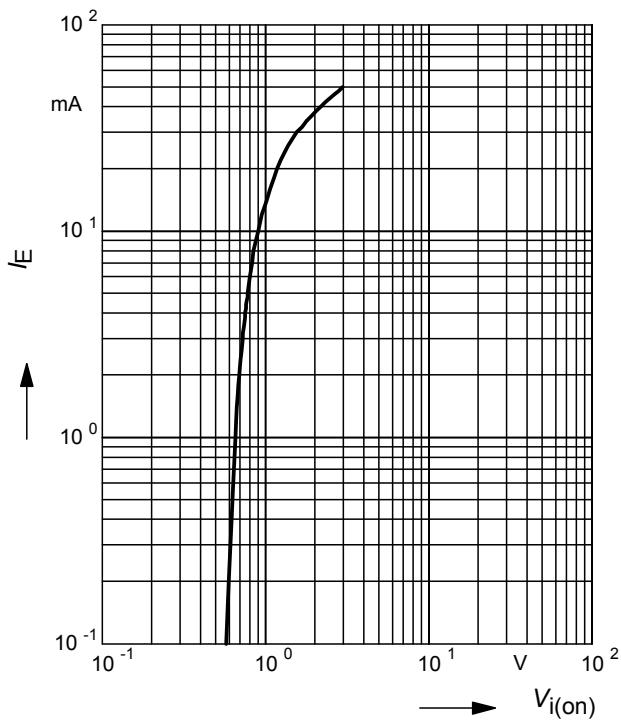
Transition frequency $I_C = 10 \text{ mA}, V_{\text{CE}} = 5 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	150	-	MHz
Collector-base capacitance $V_{\text{CB}} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{\text{cb}}$	-	3	-	pF

<sup>1</sup>Pulse test:  $t < 300\mu\text{s}$ ;  $D < 2\%$

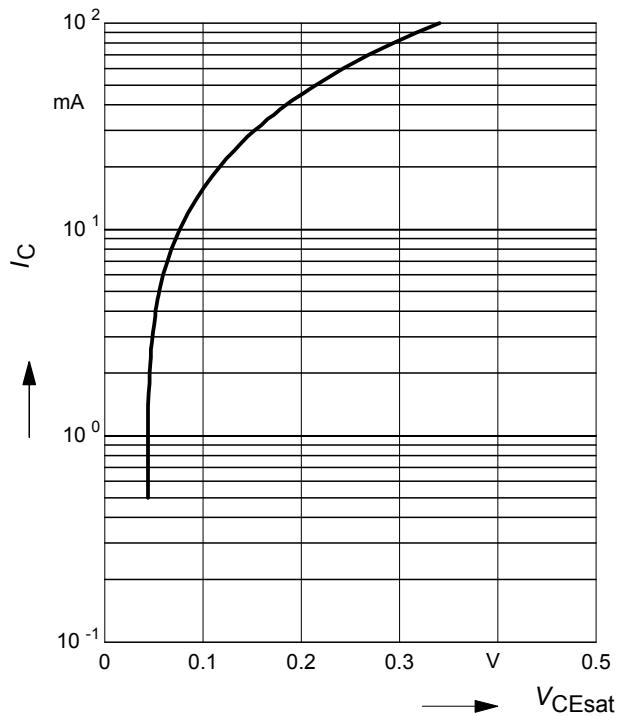
**DC current gain  $h_{FE} = f(I_C)$**   
 $V_{CE} = 5V$  (common emitter configuration)



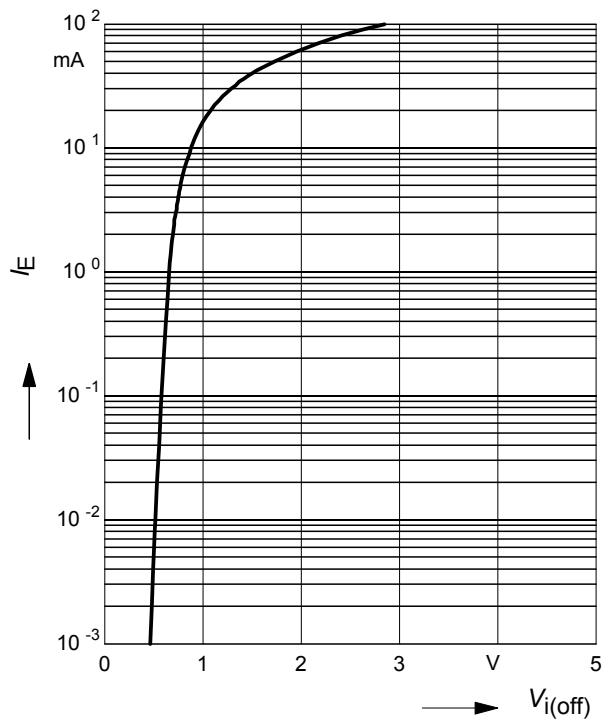
**Input on Voltage  $V_{i(on)} = f(I_C)$**   
 $V_{CE} = 0.3V$  (common emitter configuration)



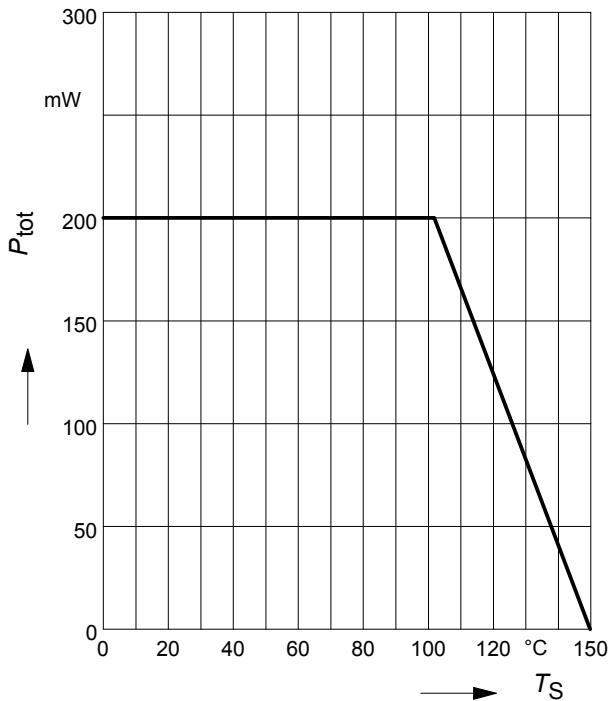
**Collector-emitter saturation voltage**  
 $V_{CEsat} = f(I_C), h_{FE} = 20$



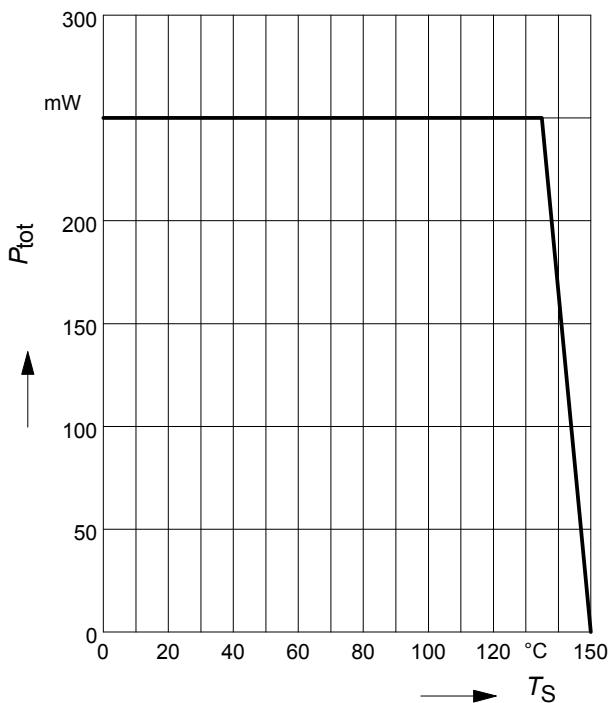
**Input off voltage  $V_{i(off)} = f(I_C)$**   
 $V_{CE} = 5V$  (common emitter configuration)



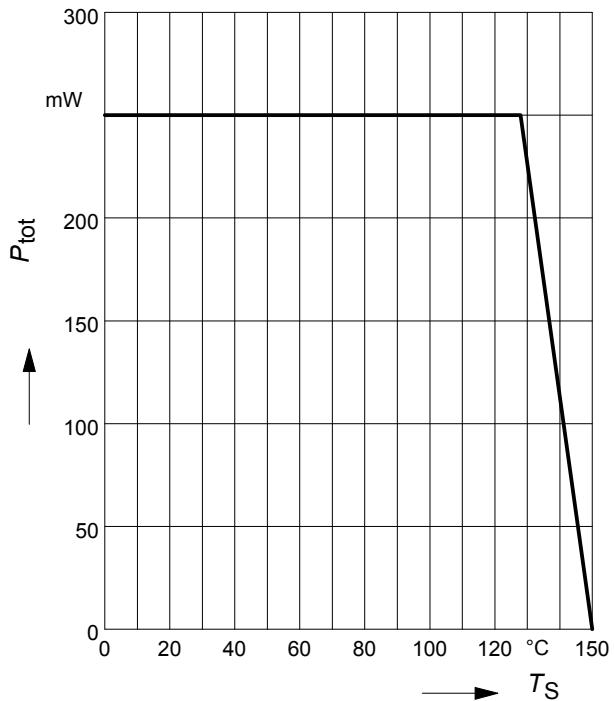
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119



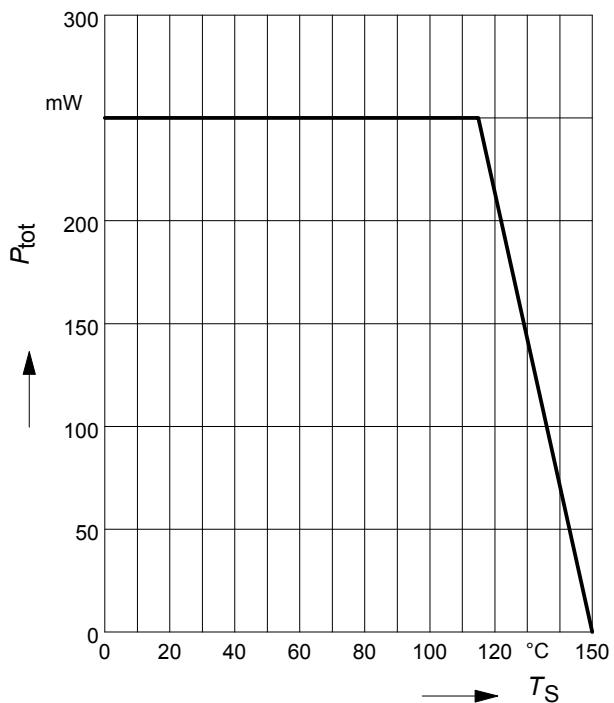
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119L3



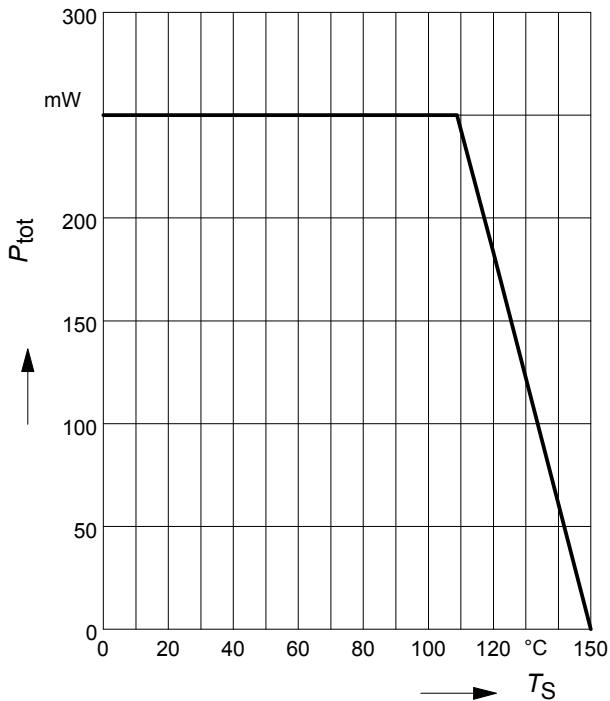
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119F



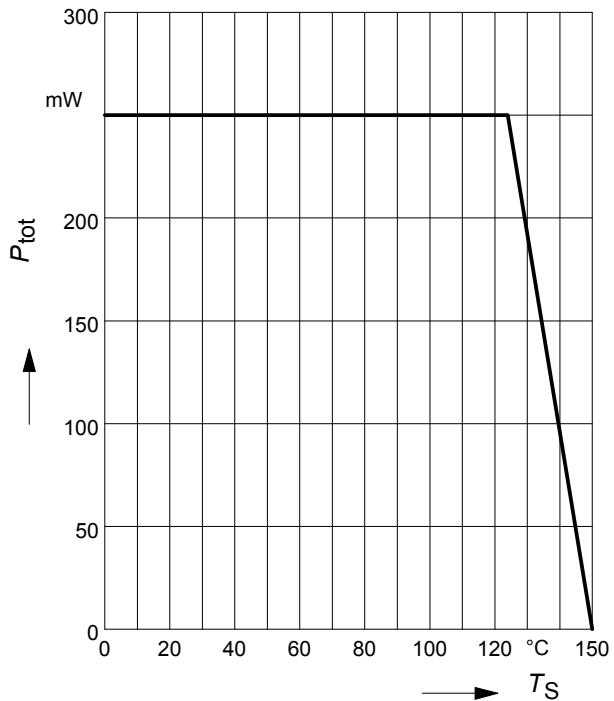
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119S



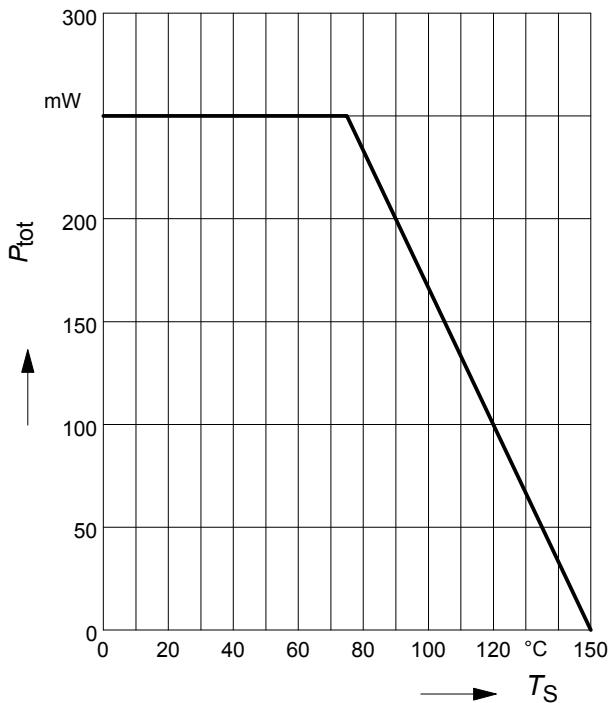
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119T



**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
BCR119W

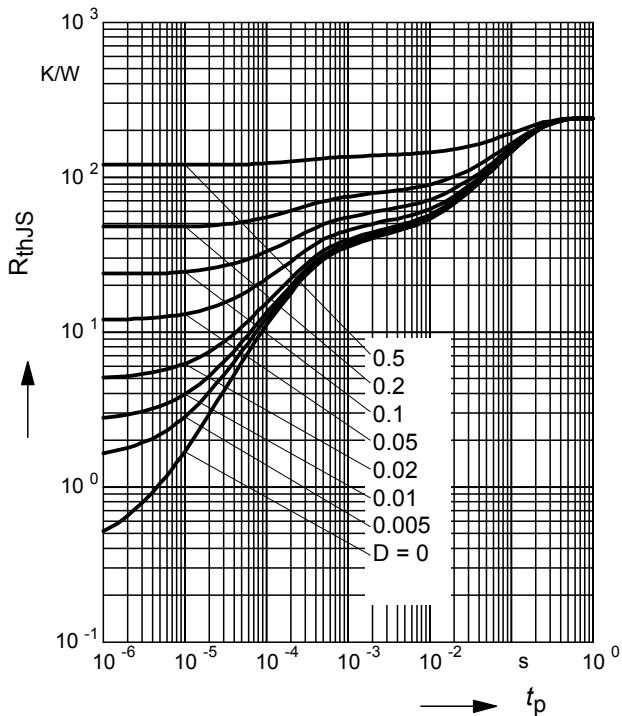


**Total power dissipation  $P_{\text{tot}} = f(T_S)$**   
SEMH7



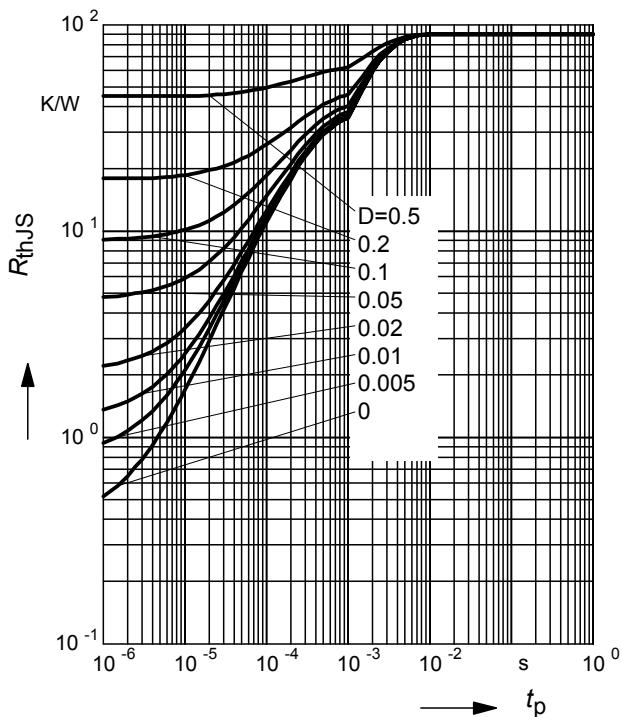
**Permissible Pulse Load**  $R_{\text{thJS}} = f(t_p)$

BCR119



**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$

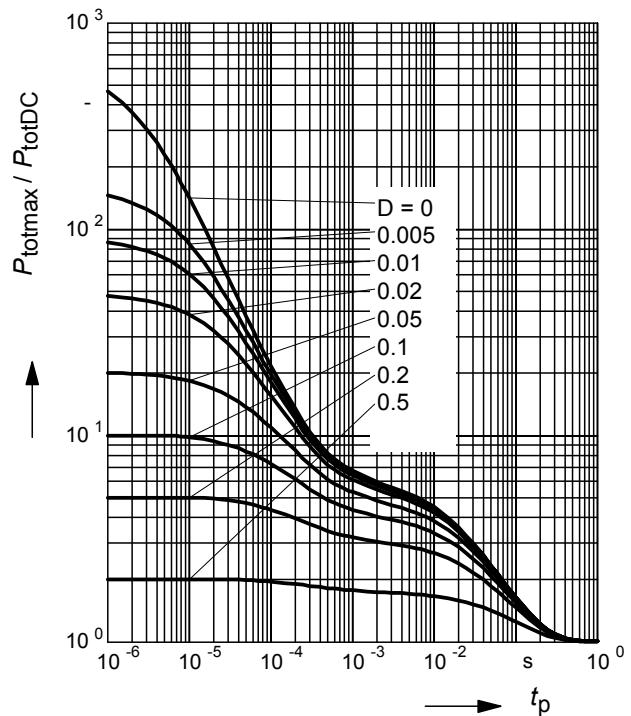
BCR119F



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

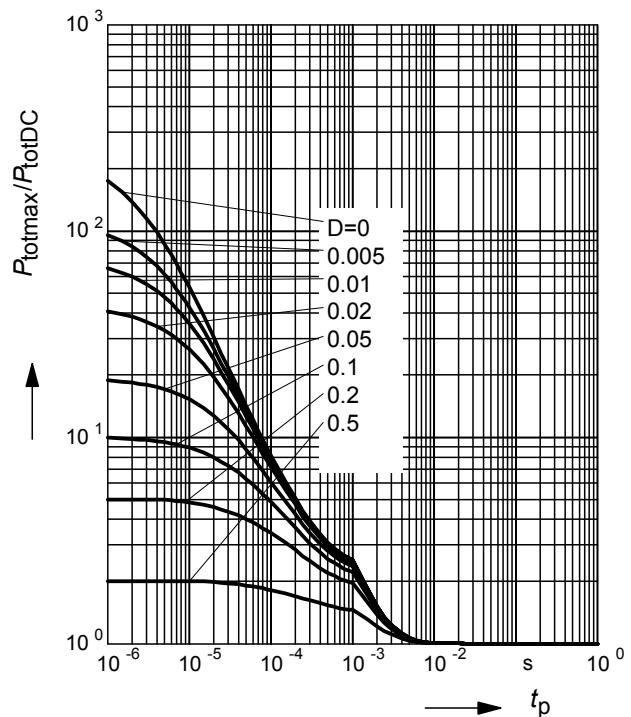
BCR119



**Permissible Pulse Load**

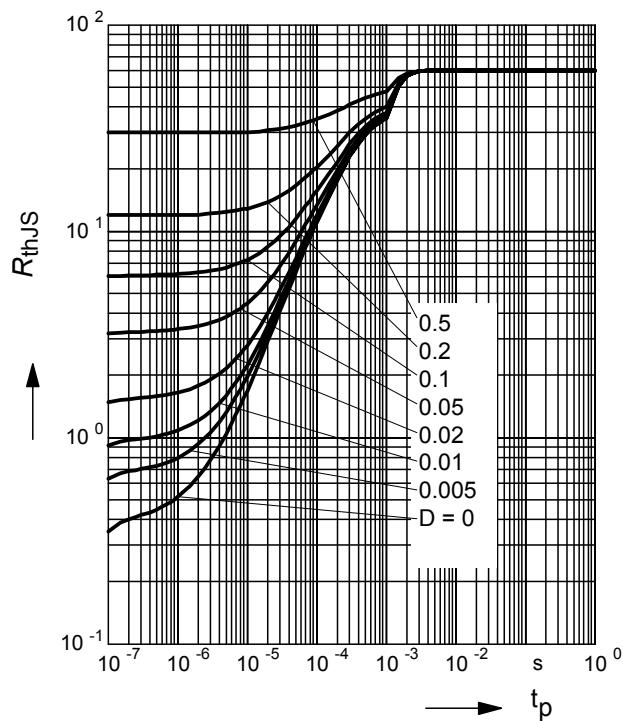
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR119F



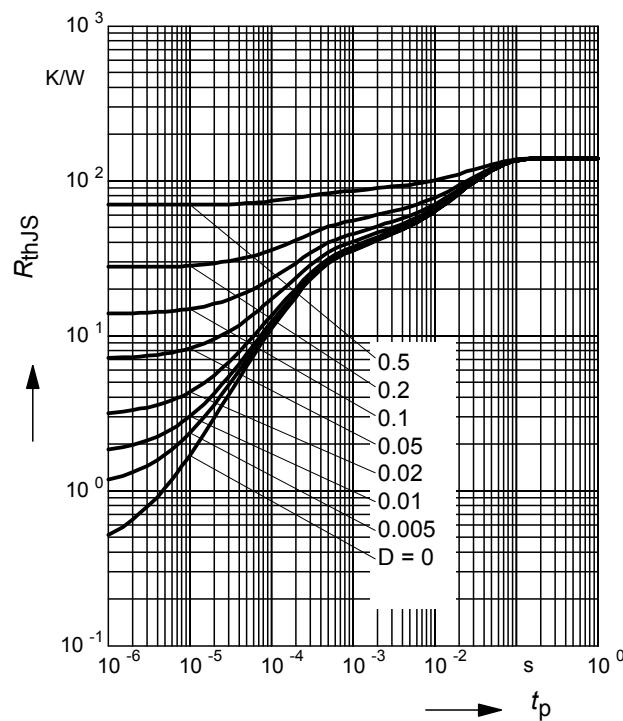
**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$

BCR119L3



**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$

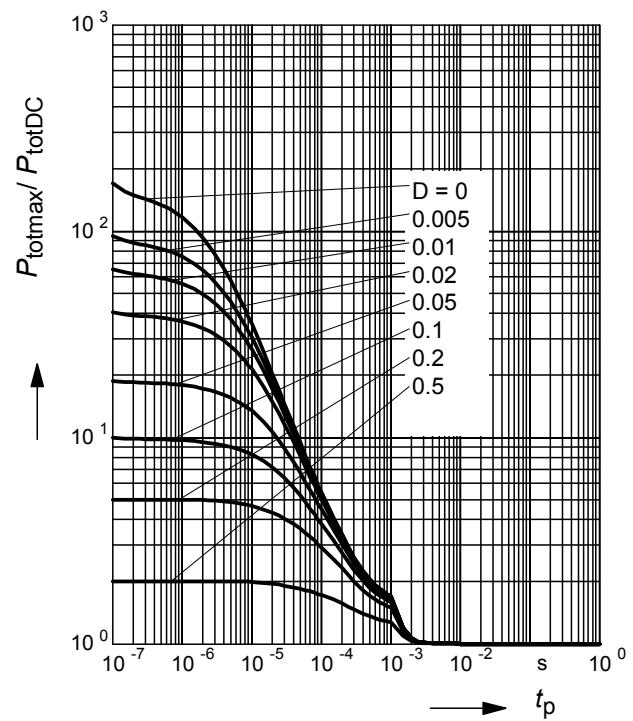
BCR119S



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

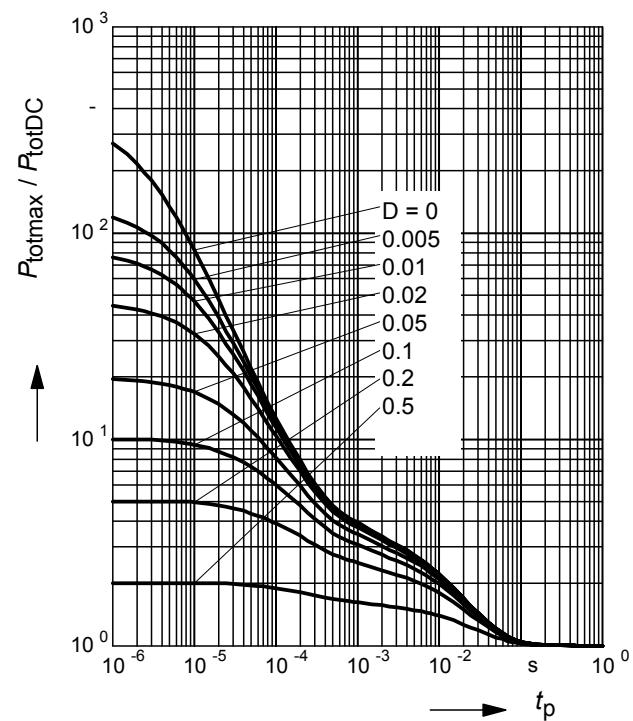
BCR119L3



**Permissible Pulse Load**

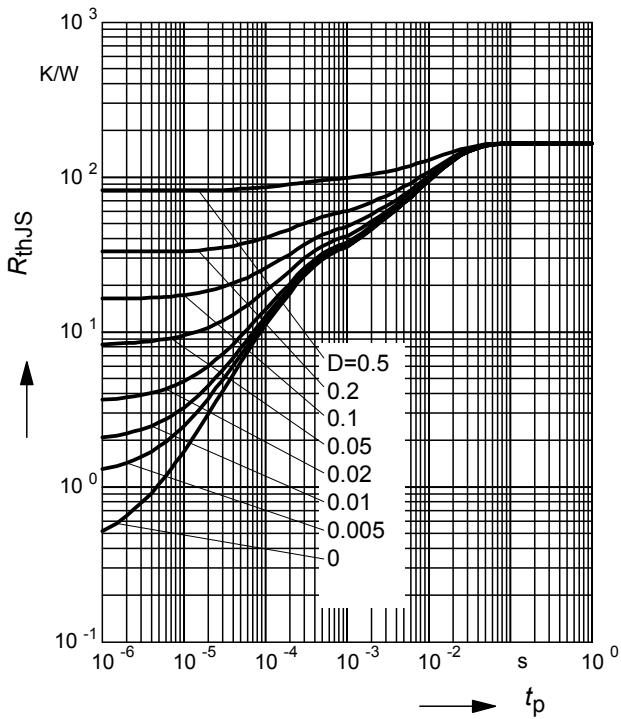
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR119S



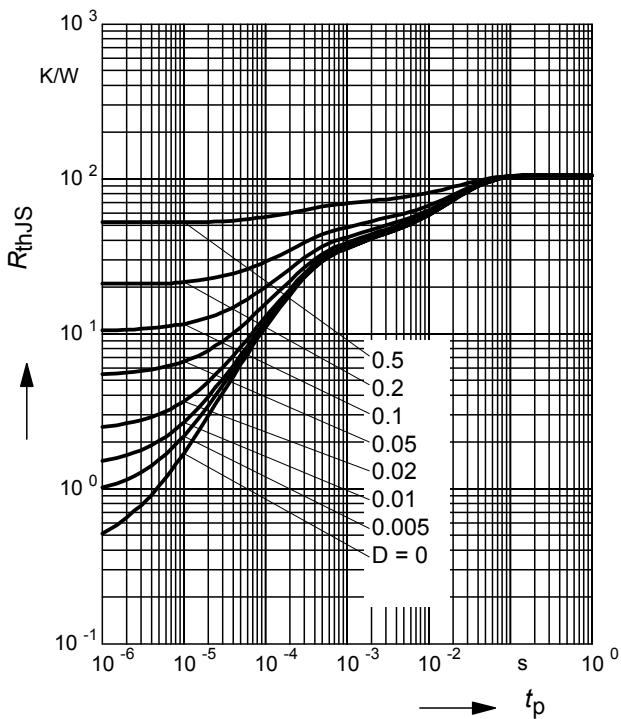
**Permissible Puls Load  $R_{thJS} = f(t_p)$**

BCR119T



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

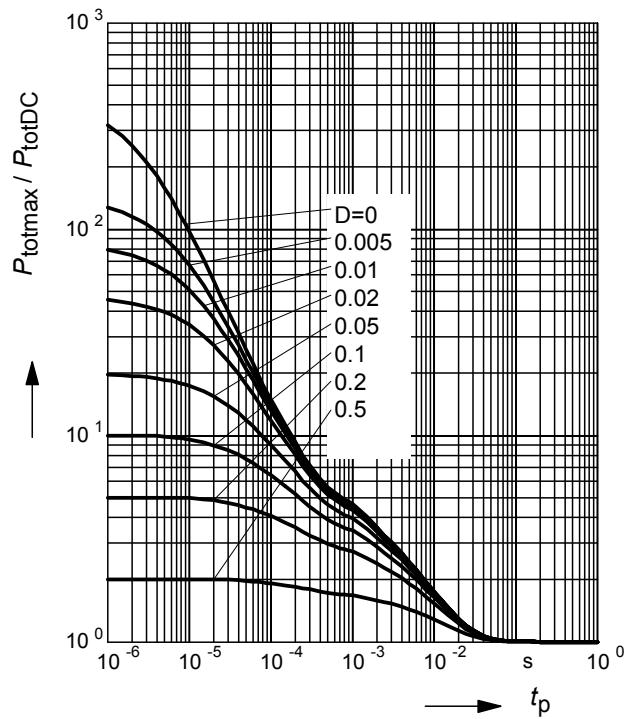
BCR119W



**Permissible Pulse Load**

$P_{totmax}/P_{totDC} = f(t_p)$

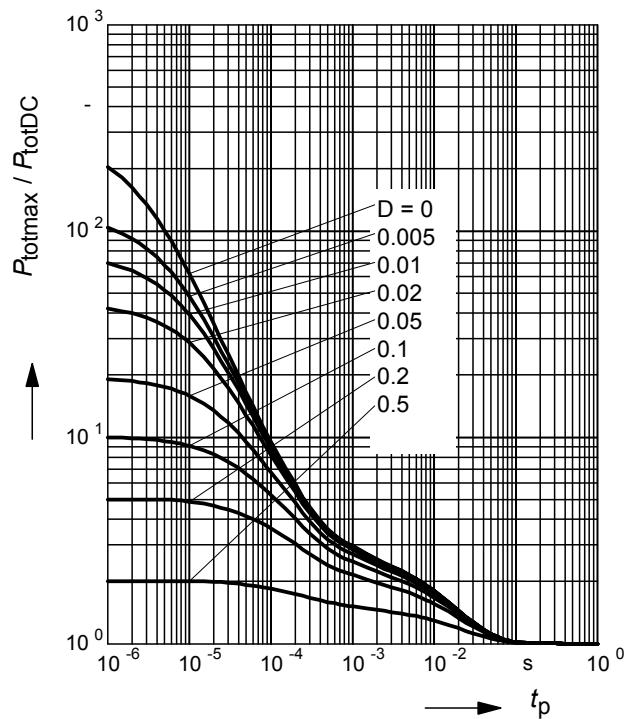
BCR119T



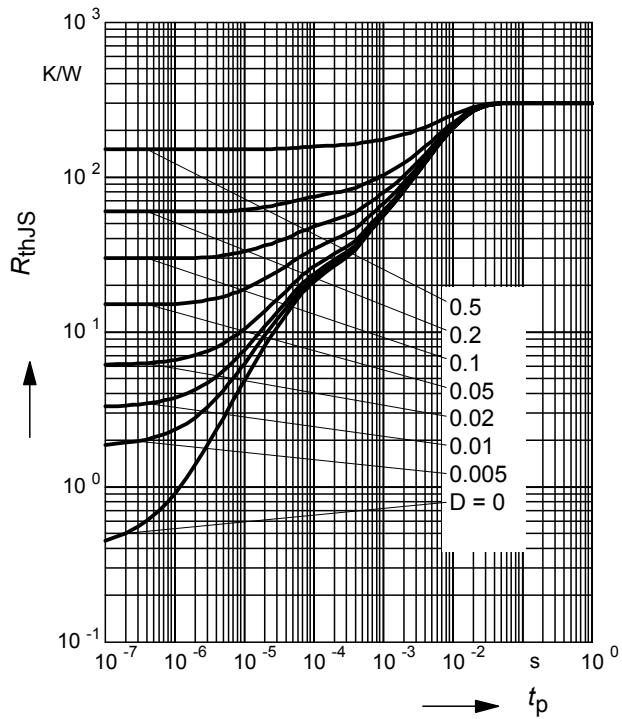
**Permissible Pulse Load**

$P_{totmax}/P_{totDC} = f(t_p)$

BCR119W



**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$   
SEMH7



**Permissible Pulse Load**  
 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$   
SEMH7

